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BOX 5120, LCD MERIVALE OTTAWA, ONTARIO CANADA K2C 3H5

## PERFORMANCE CHECKSHEET

Model: AVO-9H-B-P-P1B-T1B-W1
Type: Ultra-High-Speed Laser Diode Driver
S.N.: 13105

Date: December 17, 2013
Basic specifications: $\rightarrow$

Output Amplitude: up to +103 V , to $50 \Omega$
Pulse Width (FWHM): $1-200 \mathrm{~ns}$
Rise Time (20\%-80\%): $\leq 700$ ps
Fall Time ( $80 \%-20 \%$ ): $\leq 700 \mathrm{ps}$
PRF: $\quad 1 \mathrm{~Hz}-50 \mathrm{kHz}$
Jitter, Stability: OK
Prime Power: $\quad 100-240 V \mathrm{AC}, 50-60 \mathrm{~Hz}$.

## Test Waveforms

Mainframe output, +100V into 50 Ohms, 50 kHz, 1 ns pulse width:

2 ns/div. $50 \mathrm{~V} / \mathrm{div}(50 \mathrm{mV} / \mathrm{div} \times 60 \mathrm{~dB}$ ):


Mainframe output, +100V into 50 Ohms, 50 kHz, 20 ns pulse width:
$5 \mathrm{~ns} /$ div. $50 \mathrm{~V} / \mathrm{div}(50 \mathrm{mV} / \mathrm{div} \times 60 \mathrm{~dB}$ ):


Mainframe output, +100V into 50 Ohms, 50 kHz, 200 ns pulse width, leading edge:

2 ns/div. $50 \mathrm{~V} / \mathrm{div}(50 \mathrm{mV} / \mathrm{div} \times 60 \mathrm{~dB}$ ):


Mainframe output, +100V into 50 Ohms, 50 kHz, 200 ns pulse width, trailing edge:
$5 \mathrm{~ns} /$ div. $50 \mathrm{~V} / \mathrm{div}(50 \mathrm{mV} / \mathrm{div} \times 60 \mathrm{~dB}$ ):


With mainframe set at $+100 \mathrm{~V}, 50 \mathrm{kHz}, 50 \mathrm{~ns}$ pulse width:


Top waveform: Voltage across the parallel combination of the $4.6 \Omega$ effective resistance. It should be approximately $(+100 \mathrm{~V} / 54.6 \Omega) \times 4.6 \Omega$ $=+8.4 \mathrm{~V}$ in amplitude, which agrees with the observed waveform.

Bottom waveform: "MI" output, approximately +100V / 11.

Both: $5 \mathrm{~V} / \mathrm{div}(=50 \mathrm{mV} / \mathrm{div} \times 40 \mathrm{~dB}$ ), $10 \mathrm{~ns} / \mathrm{div}$.

| 34.3 ns | 10ns/diu |  |  | 134.3ns |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Rise | Fall | Width | Measure- | Vert Size | :M1 |
|  |  |  | ments | $50 \mathrm{mV} / \mathrm{di}$ |  |
| 401.75 | 503.77 | 50.4287 |  | Vert Offse | t:M1 |
| ps | ps | ns |  | -1.75m |  |
| Amplitude |  |  | Compare \& | Remove/Clr | Chan |
|  |  |  | References | Trace 1 | Sel |
| 82.000 |  |  |  | Aug (M1) | M1 |

Test method: Short leads are soldered to a $5.1 \Omega$ chip resistor. A coaxial cable is soldered across the resistor. The signal lead is inserted into the anode pin socket. The grounded lead is inserted into the cathode pin socket. The total effective resistor is $5.1 \Omega \| 50 \Omega\left(\mathrm{R}_{\text {scope }}\right)=4.6 \Omega$.


